## NSN 5961-01-201-6591

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-201-6591 **Inclosure Material:** Metal **Overall Length:** 1.266 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 100.0 drain to gate voltage **Current Rating Per Characteristic:** 10.00 amperes drain current and 35.00 amperes off-state current, peak **Power Rating Per Characteristic:** 60.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**